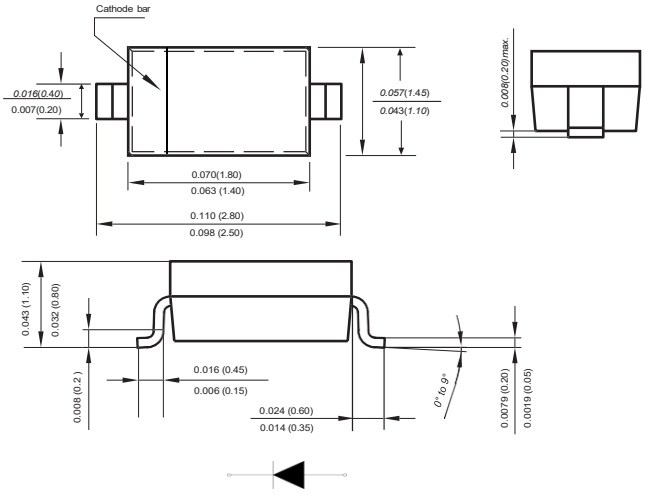
FAST SWITHING DIODES

Features

- Fast switching speed
- Surface mount package ideally suited for automatic insertion
- For general purpose switching applications
  High conductance

SOD-323



Dimensions in inches and (millimeters)

PARAMETER	SYMBOLS	BAV16WS	UNITS
Peak repetitive peak reverse voltage Working peak reverse voltage DC Blocking voltage	V_{RRM} V_{RWM} V_R	75	V
RMS Reverse voltage	$V_{R(RMS)}$	53	V
Forward continuous current	I_{FM}	300	mA
Average rectified output current	I_O	150	mA
Peak forward current @=1.0*s @=1.0s	I_{FSM}	2.0 1.0	A
Power dissipation	Pd	200	mW
Thermal resistance junction to ambient	$R_{\Theta JA}$	625	K/W
Junction temperature	T_j	125	°C
Storage temperature	T_{STG}	-65 to +150	°C
Non-Repetitive peak reverse voltage	V_{RM}	100	V

Characteristics at Ta= 25 °C

PARAMETER	SYMBOLS	Min.	Typ.	Max.	Unit	Conditions
Froward voltage	V_{F1}			0.715	V	I_F=1.0mA
	V_{F2}			0.855	V	I_F=10mA
	V_{F3}			1.0	V	I_F=50mA
	V_{F4}			1.25	V	I_F=150mA
Reverse current	I_{R1}			1	uA	V_R=75V
	I_{R2}			25	nA	V_R=20V
Capacitance between terminals	C_T			2	pF	V_R=0V,f=1.0MHz
Reverse recovery time	t_{rr}			4	ns	I_F=I_R=10mA Irr=0.1XI_R,R_L=100Ω

Typical Characterisitics

FIG. 1- FORWARD CHARACTERISTICS

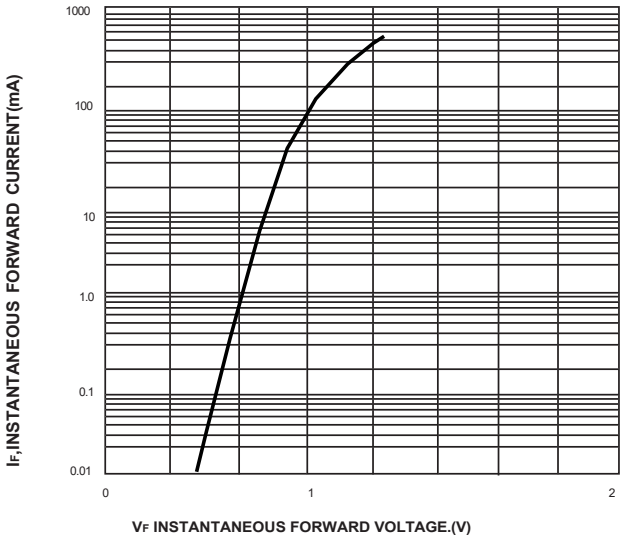
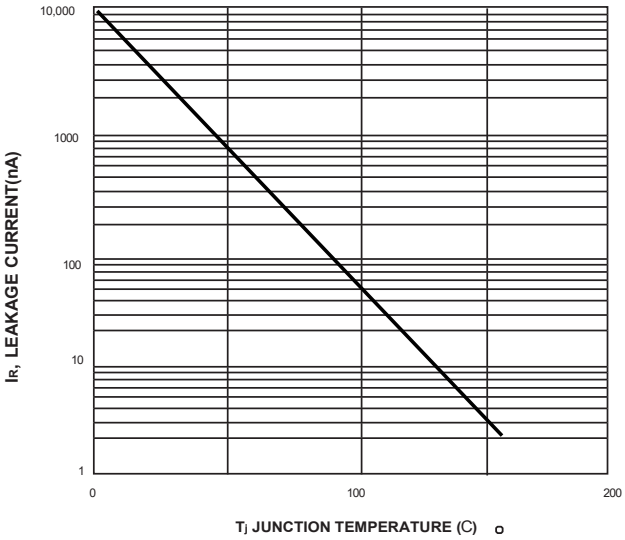


FIG. 2-LEAKAGE CURRENT VS JUNCTION TEMPERATURE



The curve above is for reference only.